

HIGH VOLTAGE POWER TRANSISTOR

The BU126 Type is a fast switching high voltage transistor, more specially intended for operating in color TV receivers chopper supplies.

FEATURES:

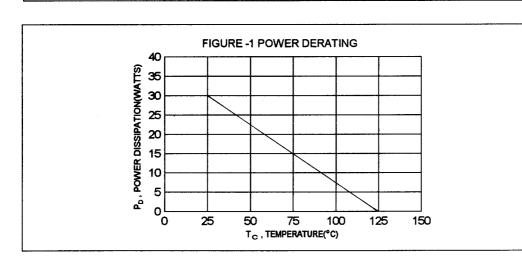
- * Continuous Collector Current- I_C= 3.0A * Power Dissipation- P_D= 30W@T_C= 25°C * DC Current Gain hFE=15(Min)@I_C= 1.0A

MAXIMUM RATINGS

Characteristic	Symbol	BU126	Unit
Collector-Base Voltage	V _{CBO}	750	V
Collector-Emitter Voltage	V _{CEO}	300	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current - Continuous -Peak	lc	3.0 5.0	A
Base Current-Continuous	l _B	2.0	Α
Total PowerDissipation@T _c =25°C Derate above 25°C	P _D	30 0.3	W/°C
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-65 to +125	°C

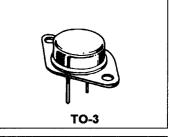
THERMAL CHARACTERISTICS

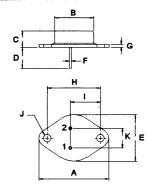
Cha	racteristic	Symbol	Max	Unit
Thermal Resista	ance Junction to Case	Re j C	3.33	°C/W



NPN **BU126**

3 AMPERE **POWER TRANSISTORS** 300 VOLTS 30 WATTS



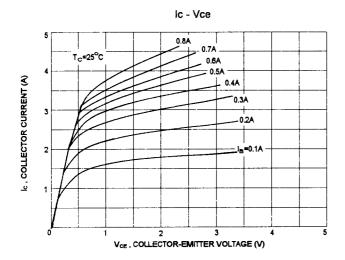


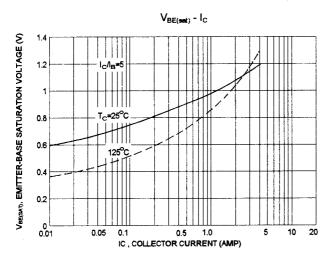
PIN 1.BASE 2.EMITTER COLLECTOR(CASE)

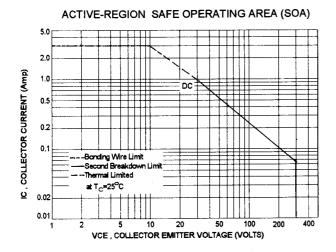
DIM	MILLIM	ETERS
ואוע	MIN	MAX
Α	38.75	39.96
В	19.28	22.23
С	7.96	9.28
D	11.18	12.19
Ε	25.20	26.67
F	0.92	1.09
G	1.38	1.62
Н	29.90	30.40
1	16.64	17.30
J	3.88	4.36
K	10.67	11.18

Characteris	tic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (I _C = 0.1A, I _B = 0, L= 25 mH)		V _{CEO (sus)}	300		V
Collector Cutoff Current (V _{CE} = 750 V, V _{BE} = 0)		I _{CES}		500	uA
Emitter Cutoff Current (V _{BE} = 6.0 V, I _C = 0)		I _{EBO}		5.0	mA
ON CHARACTERISTICS (1)					
DC Current Gain (I _C = 1.0 A, V _{CE} =5.0 V)		hFE	15	60	
Collector-Emitter Saturation Voltage (I _c = 2.5 A, I _B =0.25 A) (I _c = 4.0A,I _B =1.0 A)		V _{CE(sat)}		10 5.0	V
Base-Emitter Saturation Voltage (I _C = 4.0 A, I _B =1.0 A)		V _{BE(sat)}		1.5	V
DYNAMIC CHARACTERISTICS					
Current Gain-Bandwidth Prodct (I _C =200 mA, V _{CE} =10 V, f= 1MHz)		f _T	4.0(typ)		MHz
SWITCHING CHARACTERISTIC	S				
Storage Time	I _C = 2.5A,V _{CC} = 50V I _{B1} =-I _{B2} = 0.25A	t _s		3.0	us
Fall Time		t,		0.9	us-

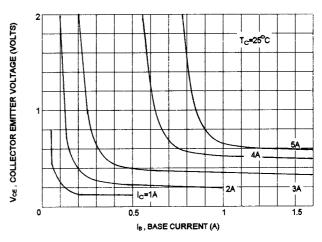
⁽¹⁾ Pulse Test: Pulse width $\ \le \ 300 \ us$, Duty Cycle $\ \le \ 2.0\%$

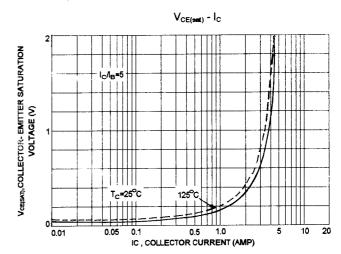












There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $I_{\text{C}}\text{-}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on $T_{J(PK)}$ =150 °C; T_c is variable depending on conditions second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)}$ ≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



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